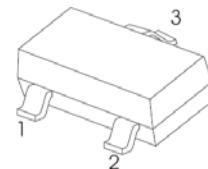


SOT-23-3L Plastic-Encapsulate MOSFETS

■ Features

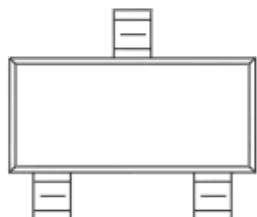
- V_{DS} (V) = -60V
- I_D = -1.25 A (V_{GS} = -10V)
- $R_{DS(ON)} < 340\text{m}\Omega$ (V_{GS} = -10V)
- $R_{DS(ON)} < 550\text{m}\Omega$ (V_{GS} = -4.5V)
- Pb-Free Package May be Available. The G-Suffix Denotes a Pb-Free Lead Finish

SOT - 23

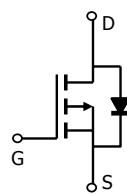


1. GATE
2. SOURCE
3. DRAIN

MARKING



Equivalent Circuit

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

| Parameter | Symbol | Rating | Unit |
|---|------------|------------|------|
| Drain-Source Voltage | V_{DS} | -60 | V |
| Gate-Source Voltage | V_{GS} | ± 20 | |
| Continuous Drain Current *1,*2 | I_D | -1.25 | A |
| $T_a = 70^\circ\text{C}$ | | -0.85 | |
| Pulsed Drain Current | I_{DM} | -8 | A |
| Avalanche Current $L=0.1\text{mH}$ | I_{AS} | -5 | |
| Power Dissipation *1,*2 | P_D | 1.25 | W |
| $T_a = 25^\circ\text{C}$ | | 0.8 | |
| Thermal Resistance.Junction- to-Ambient $t \leqslant 5 \text{ sec}$ | R_{thJA} | 100 | °C/W |
| Steady State *1 | | 166 | |
| Thermal Resistance.Junction- to-Case *1 | R_{thJC} | 60 | °C |
| Junction Temperature | T_J | 150 | |
| Storage Temperature Range | T_{stg} | -55 to 150 | |

*1 Surface Mounted on FR4 Board.

*2 $t \leqslant 5 \text{ sec.}$

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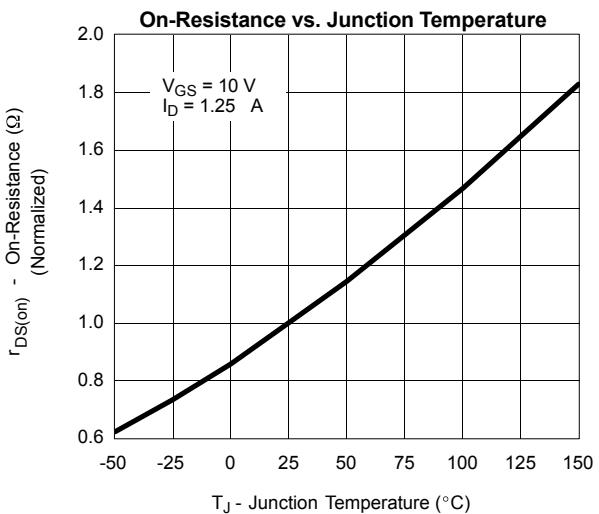
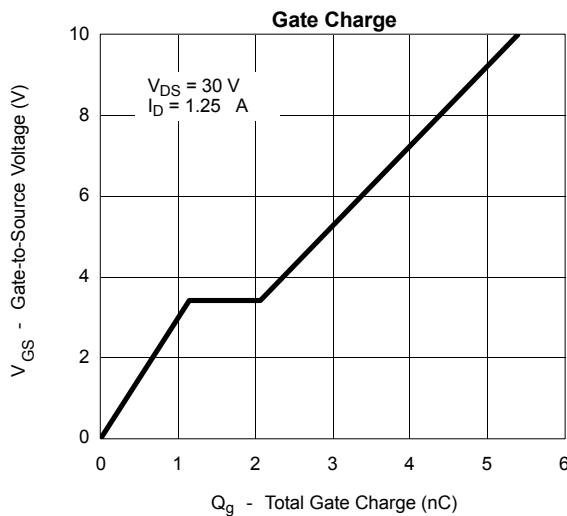
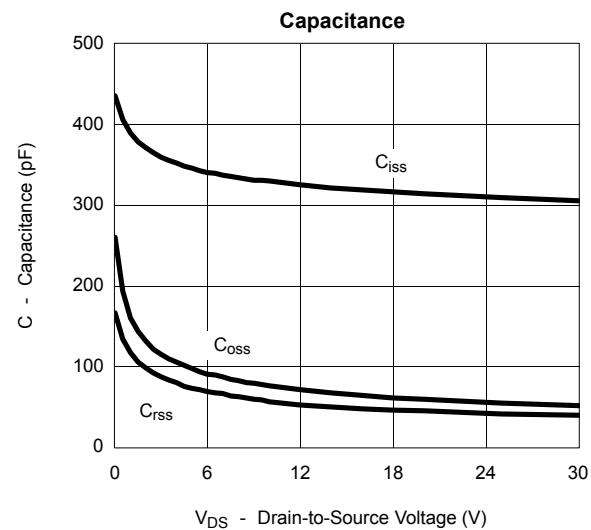
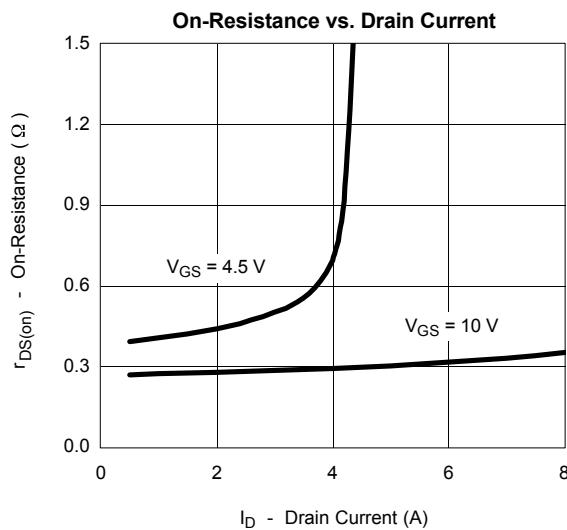
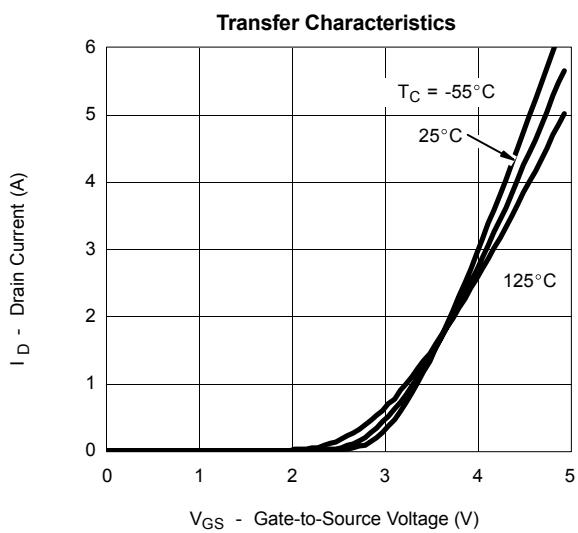
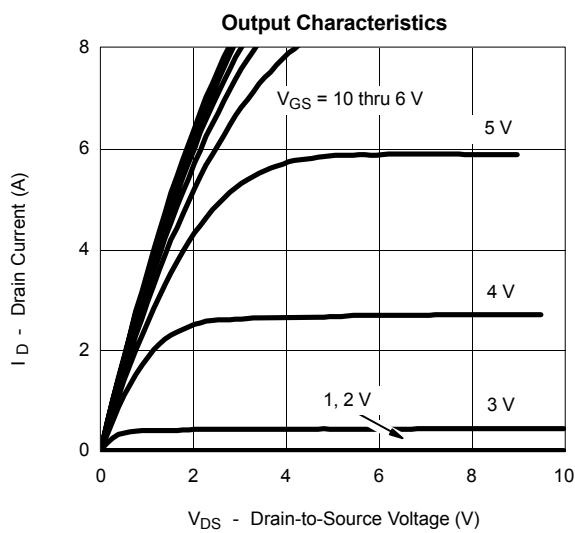
■ Electrical Characteristics $T_a = 25^\circ\text{C}$

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|---------------------------------------|--------------|--|-----|-------|-----------|------------------|
| Drain-Source Breakdown Voltage | V_{DSS} | $I_D=-250 \mu\text{A}, V_{GS}=0\text{V}$ | -60 | | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS}=-48\text{V}, V_{GS}=0\text{V}$ | | | -1 | μA |
| | | $V_{DS}=-48\text{V}, V_{GS}=0\text{V}, T_J=125^\circ\text{C}$ | | | -50 | |
| Gate-Body leakage current | I_{GSS} | $V_{DS}=0\text{V}, V_{GS}=\pm 20\text{V}$ | | | ± 100 | nA |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=-250 \mu\text{A}$ | -1 | | -3 | V |
| Static Drain-Source On-Resistance *1 | $R_{DS(on)}$ | $V_{GS}=-10\text{V}, I_D=-1.25\text{A}$ | | | 340 | $\text{m}\Omega$ |
| | | $V_{GS}=-4.5\text{V}, I_D=-1\text{A}$ | | | 550 | |
| On state drain current *1 | $I_{D(ON)}$ | $V_{GS}=-4.5\text{V}, V_{DS}=-10\text{V}$ | -6 | | | A |
| Forward Transconductance *1 | g_{FS} | $V_{DS}=-4.5\text{V}, I_D=-1\text{A}$ | | 1.9 | | S |
| Total Gate Charge | Q_g | $V_{GS}=-10\text{V}, V_{DS}=-30\text{V}, I_D=-1.25\text{A}$ | | 5.4 | 12 | nC |
| Gate Source Charge | Q_{gs} | | | 1.15 | | |
| Gate Drain Charge | Q_{gd} | | | 0.92 | | |
| Turn-On DelayTime | $t_{d(on)}$ | $V_{GS}=-4.5\text{V}, V_{DS}=-30\text{V}, R_L=30 \Omega, R_{GEN}=6 \Omega$ $I_D=-1\text{A}$ | | 10.5 | 20 | ns |
| Turn-On Rise Time | t_r | | | 11.5 | 20 | |
| Turn-Off DelayTime | $t_{d(off)}$ | | | 15.5 | 30 | |
| Turn-Off Fall Time | t_f | | | 7.5 | 15 | |
| Body Diode Reverse Recovery Time | t_{rr} | $I_F=-1.25\text{A}, dI/dt=100\text{A}/\mu\text{s}$ | | 30 | 55 | |
| Maximum Body-Diode Continuous Current | I_s | | | | -1.25 | A |
| Diode Forward Voltage | V_{SD} | $I_s=-1.25\text{A}, V_{GS}=0\text{V}$ | | -0.82 | -1.2 | V |

*1 Pulse test; pulse width $\leq 300\text{us}$, duty cycle $\leq 2\%$.

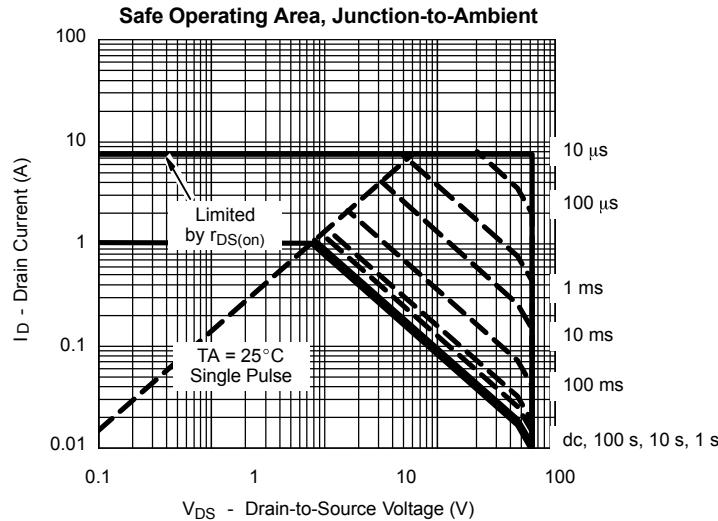
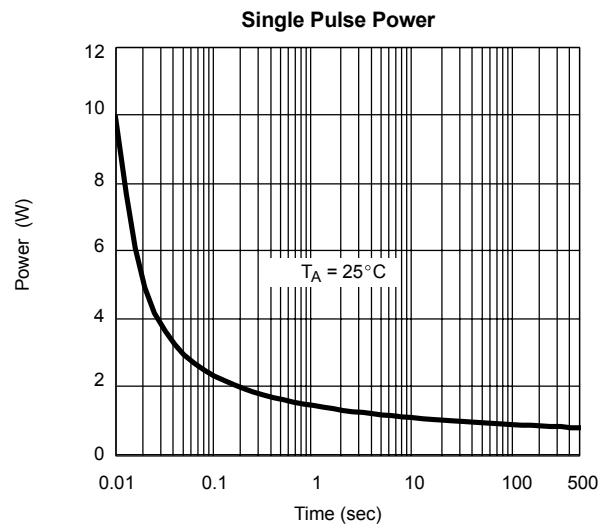
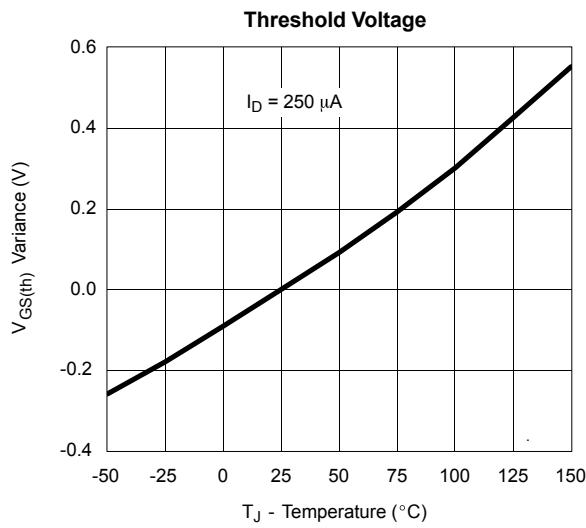
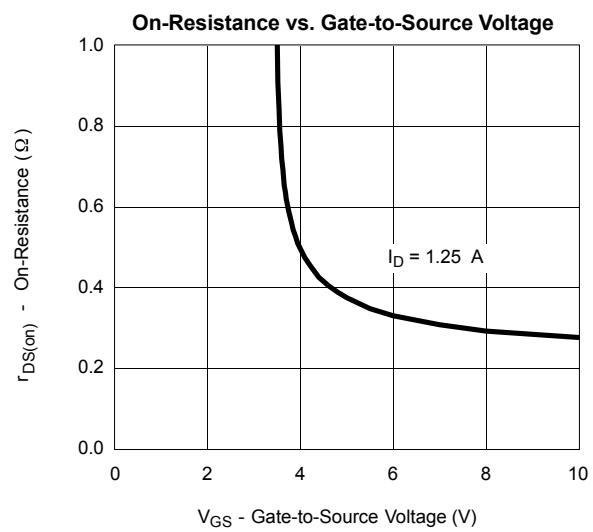
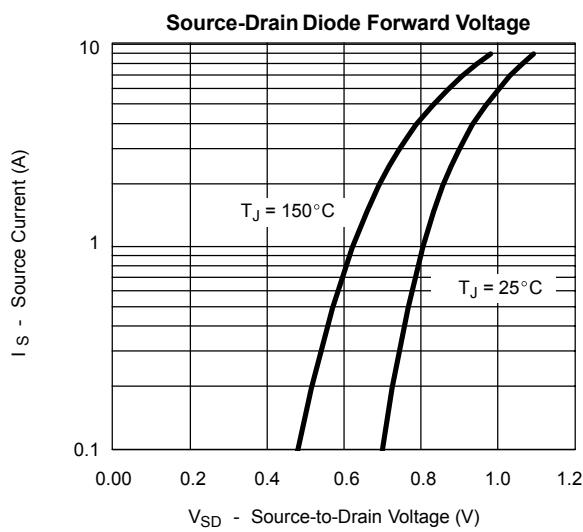
SOT-23-3L Plastic-Encapsulate MOSFETS

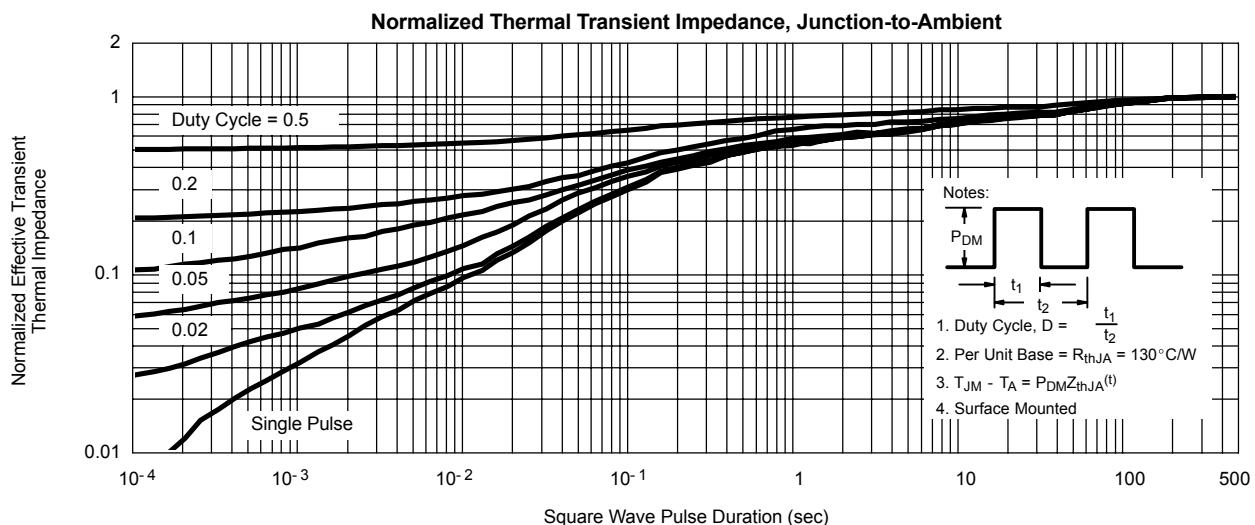
■ Typical Characteristics



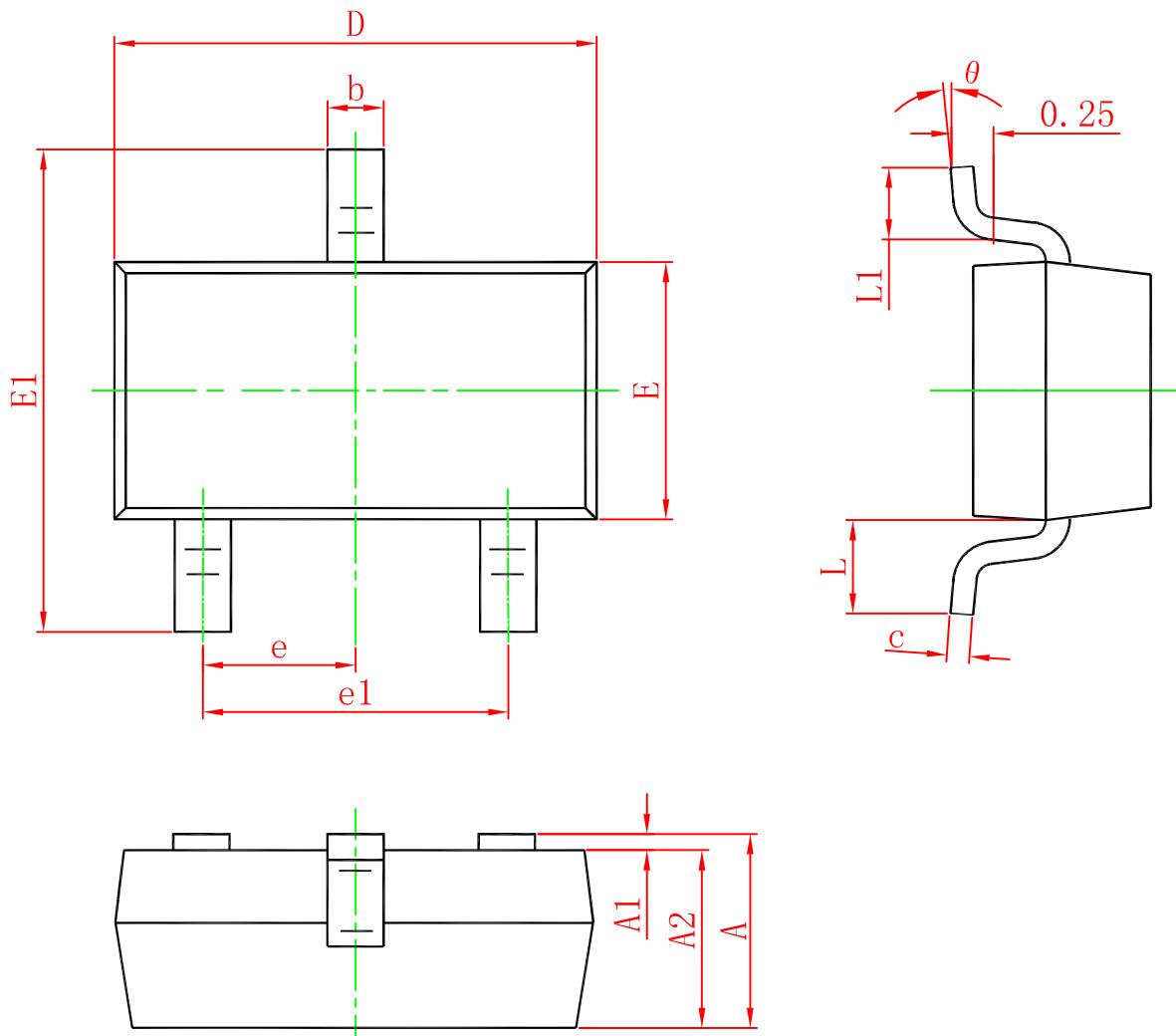
SOT-23-3L Plastic-Encapsulate MOSFETS

■ Typical Characteristics



SOT-23-3L Plastic-Encapsulate MOSFETS**■ Typical Characteristics**

SOT-23 PACKAGE OUTLINE DIMENSIONS



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min. | Max. | Min. | Max. |
| A | 0.900 | 1.150 | 0.035 | 0.045 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| A2 | 0.900 | 1.050 | 0.035 | 0.041 |
| b | 0.300 | 0.500 | 0.012 | 0.020 |
| c | 0.080 | 0.150 | 0.003 | 0.006 |
| D | 2.800 | 3.000 | 0.110 | 0.118 |
| E | 1.200 | 1.400 | 0.047 | 0.055 |
| E1 | 2.250 | 2.550 | 0.089 | 0.100 |
| e | 0.950 TYP. | | 0.037 TYP. | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 |
| L | 0.550 REF. | | 0.022 REF. | |
| L1 | 0.300 | 0.500 | 0.012 | 0.020 |
| θ | 0° | 8° | 0° | 8° |